NSN 5961-00-554-8212

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View Online at https://aerobasegroup.com/nsn/5961-00-554-8212 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 10.0 collector to emitter voltage/static/base open and 20.0 collector to base voltage, dc and 3.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 350.0 milliwatts small-signal input power, common-collector absolute **Transfer Ratio:** 10.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Lead surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

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